

Features

- Floating channel designed for bootstrap operation Fully operational to +600V
 Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout
- CMOS Schmitt-triggered inputs with pull-down
- Output in phase with input (IR2117) or out of phase with input (IR2118)

Description

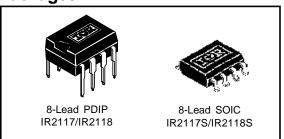
The IR2117/IR2118(S) is a high voltage, high speed power MOSFET and IGBT driver. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS outputs. The output driver features a high pulse current buffer stage designed for minimum cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high or low side configuration which operates up to 600 volts.

SINGLE CHANNEL DRIVER

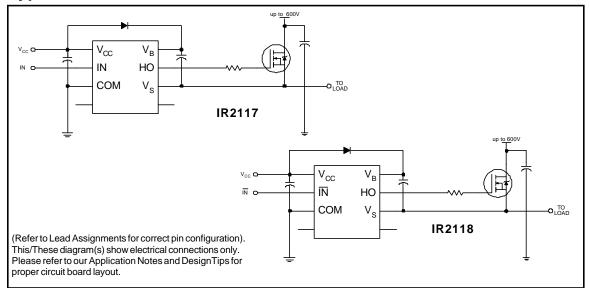
Product Summary

Voffset	600V max.
IO+/-	200 mA / 420 mA
Vout	10 - 20V
ton/off (typ.)	125 & 105 ns

Packages



Typical Connection



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Additional information is shown in Figures 5 through 8.

Symbol	Definition		Min.	Max.	Units
VB	High side floating supply voltage		-0.3	625	
٧s	High side floating supply offset voltage		V _B - 25	V _B + 0.3	
Vно	High side floating output voltage		Vs - 0.3	V _B + 0.3	V
Vcc	Logic supply voltage		-0.3	25	
VIN	Logic input voltage		-0.3	VCC + 0.3	
dV _S /dt	Allowable offset supply voltage transient (fig	gure 2)	_	50	V/ns
PD	Package power dissipation @ T _A ≤ +25°C	(8 lead PDIP)	_	1.0	
		(8 lead SOIC)	_	0.625	W
RthJA	Thermal resistance, junction to ambient	(8 lead PDIP)	_	125	°C/W
		(8 lead SOIC)	_	200	0, 11
TJ	Junction temperature		_	150	
TS	Storage temperature		-55	150	°C
TL	Lead temperature (soldering, 10 seconds)		_	300	

Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The Vs offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
VB	High side floating supply absolute voltage	Vs + 10	Vs + 20	
٧s	High side floating supply offset voltage	Note 1	600	
Vно	High side floating output voltage	٧s	VB	V
Vcc	Logic supply voltage	10	20	
VIN	Logic input voltage	0	Vcc	
TA	Ambient temperature	-40	125	°C

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to -VBS. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified. The dynamic electrical characteristics are measured using the test circuit shown in Figure 3.

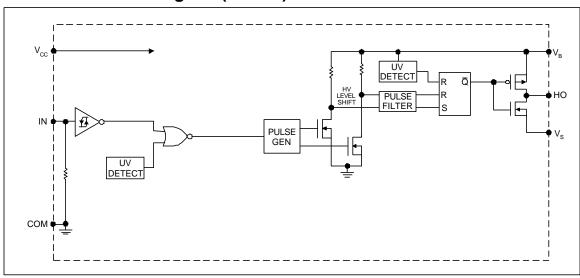
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
ton	Turn-on propagation delay	_	125	200		Vs = 0V
t _{off}	Turn-off propagation delay	_	105	180		Vs = 600V
t _r	Turn-on rise time	_	80	130	ns	
t _f	Turn-off fall time	_	40	65		

Static Electrical Characteristics

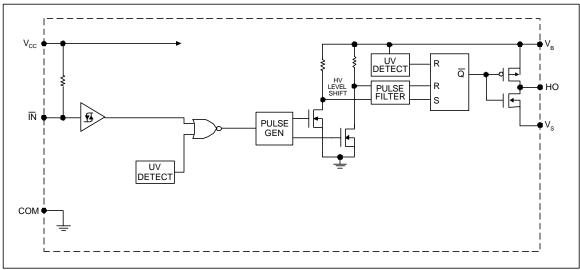
 V_{BIAS} (VCC, V_{BS}) = 15V and T_A = 25°C unless otherwise specified. The V_{IN} , V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
VIH	input voltage - logic "1" (IR2117) logic "0" (IR2118)	9.5	_	_	. V	
VIL	Input voltage - logic "0" (IR2117) logic "1" (IR2118)	_	_	6.0	·	
Voн	High level output voltage, VBIAS - VO	_	_	100	mV	IO = 0A
Vol	Low level output voltage, VO	_	_	100	IIIV	IO = 0A
ILK	Offset supply leakage current	_	_	50		V _B = V _S = 600V
IQBS	Quiescent V _{BS} supply current	_	50	240		VIN = 0V or VCC
IQCC	Quiescent V _{CC} Supply Current	_	70	340		VIN = 0V or VCC
I _{IN+}	Logic "1" input bias current (IR2117)		20	40	μΑ	VIN = VCC
	(IR2118)		20	10		VIN = 0V
I _{IN} -	Logic "0" input bias current (IR2117)			1.0		VIN = 0V
	(IR2118)					VIN = VCC
V _{BSUV+}	VBS supply undervoltage positive going threshold	7.6	8.6	9.6		
VBSUV-	VBS supply undervoltage negative going threshold		8.2	9.2	V	
Vccuv+	VCC supply undervoltage positive going threshold	7.6	8.6	9.6	ľ	
VCCUV-	V _{CC} supply undervoltage negative going threshold	7.2	8.2	9.2		
IO+	Output high short circuit pulsed current	200	250	_		VO = 0V
						V _{IN} = Logic "1"
					A	PW ≤ 10 μs
I _O -	Output low short circuit pulsed current	420	500	_	mA	V _O = 15V
						V _{IN} = Logic "0"
						PW ≤ 10 µs

Functional Block Diagram (IR2117)



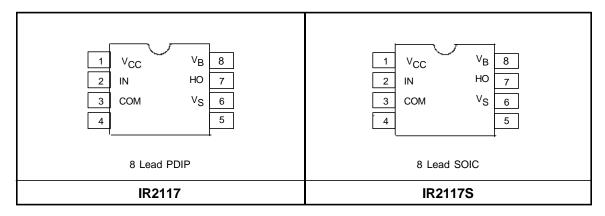
Functional Block Diagram (IR2118)

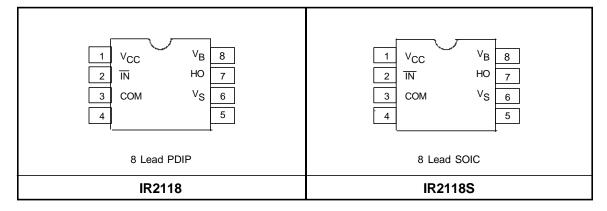


Lead Definitions

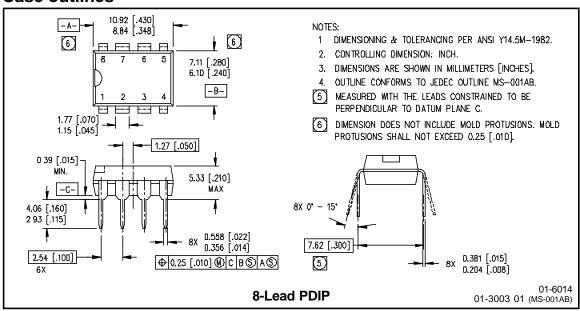
Symbol	Description
V _{CC}	Logic and gate drive supply
IN	Logic input for gate driver output (HO), in phase with HO (IR2117)
ĪN	Logic input for gate driver output (HO), out of phase with HO (IR2118)
COM	Logic ground
VB	High side floating supply
НО	High side gate drive output
٧s	High side floating supply return

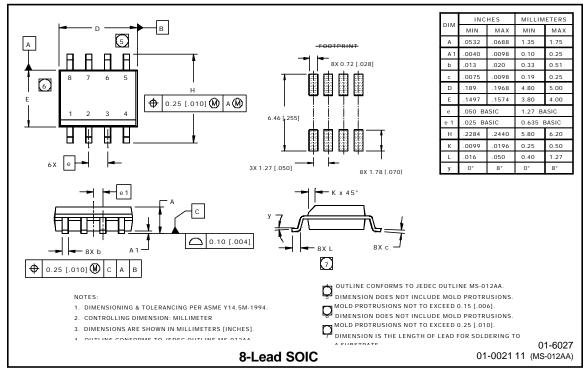
Lead Assignments





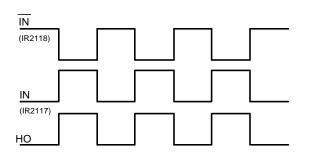
Case outlines





Internationa TOR Rectifier

IR2117/IR2118 (S)



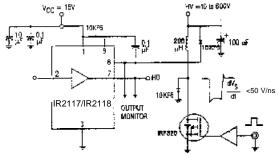


Figure 1. Input/Output Timing Diagram

Figure 2. Floating Supply Voltage Transient Test Circuit

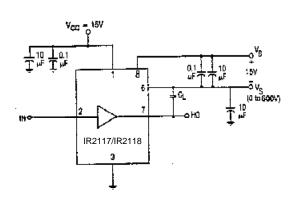


Figure 3. Switching Time Test Circuit

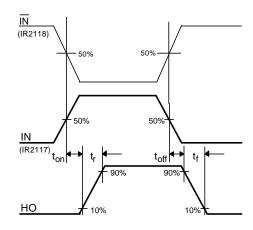


Figure 4. Switching Time Waveform Definition

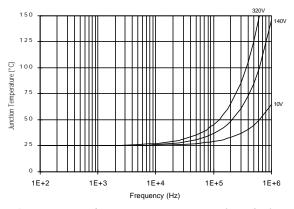


Figure 5. IR2117/IR2118 T_J vs. Frequency (IRFBC20) $R_{GATE} = 33\Omega, Vcc = 15V$

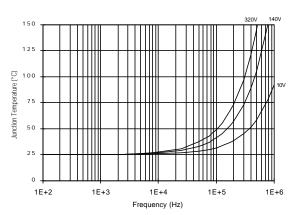


Figure 6. IR2117/IR2118 TJ vs. Frequency (IRFBC30) $$\rm R_{GATE}=22\Omega,\,Vcc=15V$$

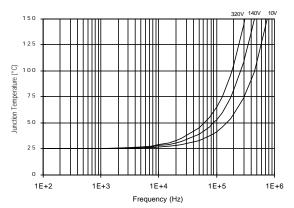


Figure 7. IR2117/IR2118 T_J vs. Frequency (IRFBC40) $R_{GATE} = 15\Omega, Vcc = 15V$

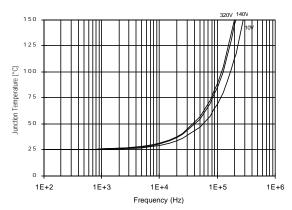


Figure 8. IR2117/IR2118 T_J vs. Frequency (IRFPE50) $R_{GATE} = 10\Omega, Vcc = 15V$

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Data and specifications subject to change without notice. 1/24/2002